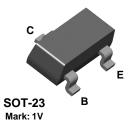


2N6427

MMBT6427





NPN Darlington Transistor

This device is designed for applications requiring extremely high current gain at collector currents to 1.0 A. Sourced from Process 05. See MPSA14 for characteristics.

Absolute Maximum Ratings*

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	40	V
V _{CBO}	Collector-Base Voltage	40	V
V _{EBO}	Emitter-Base Voltage	12	V
I _C	Collector Current - Continuous	1.2	A
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	М	Units	
		2N6427	*MMBT6427	
P_D	Total Device Dissipation Derate above 25°C	625 5.0	350 2.8	mW mW/∘C
R _{θJC}	Thermal Resistance, Junction to Case	83.3		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	°C/W

^{*}Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

¹⁾ These ratings are based on a maximum junction temperature of 150 degrees C.

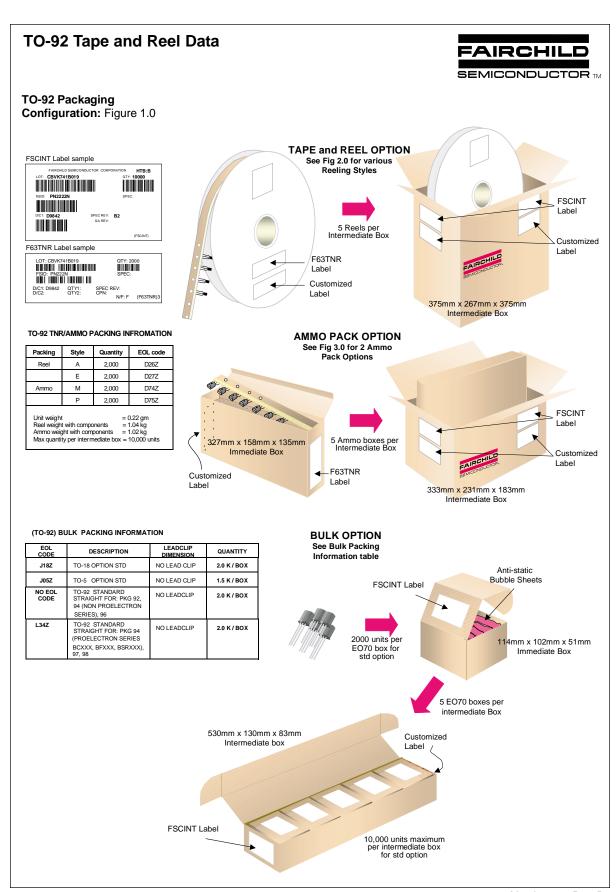
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

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NPN Darlington Transistor (continued)

Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHA	RACTERISTICS				
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0$	40		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_C = 100 \mu A, I_E = 0$	40		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E = 10 \mu A, I_C = 0$	12		V
I _{CEO}	Collector Cutoff Current	$V_{CE} = 25 \text{ V}, I_{B} = 0$		1.0	μΑ
I _{CBO}	Collector Cutoff Current	$V_{CB} = 30 \text{ V}, I_{E} = 0$		50	nA
I _{EBO}	Emitter Cutoff Current	$V_{EB} = 10 \text{ V}, I_{C} = 0$		50	nA
ON CHAR	ACTERISTICS	10			
ON CHAR	ACTERISTICS DC Current Gain*	$I_{C} = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}$	10,000	100,000	
		$I_C = 100 \text{ mA}, V_{CE} = 5.0 \text{ V}$	20,000	200,000	
h _{FE}		$\begin{split} I_{C} &= 100 \text{ mA}, \ V_{CE} = 5.0 \text{ V} \\ I_{C} &= 500 \text{ mA}, \ V_{CE} = 5.0 \text{ V} \\ I_{C} &= 50 \text{ mA}, \ I_{B} = 0.5 \text{ mA} \end{split}$,		V
	DC Current Gain*	$I_C = 100 \text{ mA}, V_{CE} = 5.0 \text{ V}$ $I_C = 500 \text{ mA}, V_{CE} = 5.0 \text{ V}$	20,000	200,000 140,000 1.2	•
h_{FE} $V_{CE(sat)}$	DC Current Gain* Collector-Emitter Saturation Voltage	$\begin{split} &I_{C} = 100 \text{ mA}, \ V_{CE} = 5.0 \text{ V} \\ &I_{C} = 500 \text{ mA}, \ V_{CE} = 5.0 \text{ V} \\ &I_{C} = 50 \text{ mA}, \ I_{B} = 0.5 \text{ mA} \\ &I_{C} = 500 \text{ mA}, \ I_{B} = 0.5 \text{ mA} \end{split}$	20,000	200,000 140,000 1.2 1.5	V
h_{FE} $V_{CE(sat)}$ $V_{BE(sat)}$	DC Current Gain* Collector-Emitter Saturation Voltage Base-Emitter Saturation Voltage	$\begin{split} &I_{C} = 100 \text{ mA}, \ V_{CE} = 5.0 \text{ V} \\ &I_{C} = 500 \text{ mA}, \ V_{CE} = 5.0 \text{ V} \\ &I_{C} = 500 \text{ mA}, \ I_{B} = 0.5 \text{ mA} \\ &I_{C} = 500 \text{ mA}, \ I_{B} = 0.5 \text{ mA} \\ &I_{C} = 500 \text{ mA}, \ I_{B} = 0.5 \text{ mA} \end{split}$	20,000	200,000 140,000 1.2 1.5 2.0	V

^{*}Pulse Test: Pulse Width $\leq\!300~\mu\text{s},$ Duty Cycle $\leq\!2.0\%$

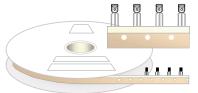


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TO-92 Tape and Reel Data, continued

TO-92 Reeling Style Configuration: Figure 2.0

Machine Option "A" (H)



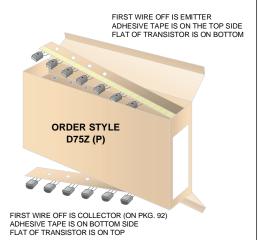
Style "A", D26Z, D70Z (s/h)

Machine Option "E" (J)

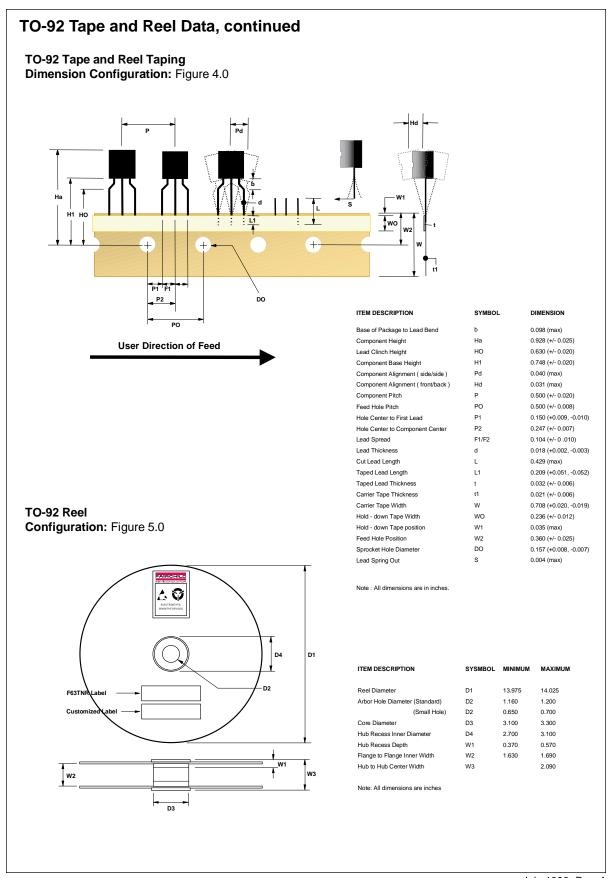
Style "E", D27Z, D71Z (s/h)

TO-92 Radial Ammo Packaging Configuration: Figure 3.0





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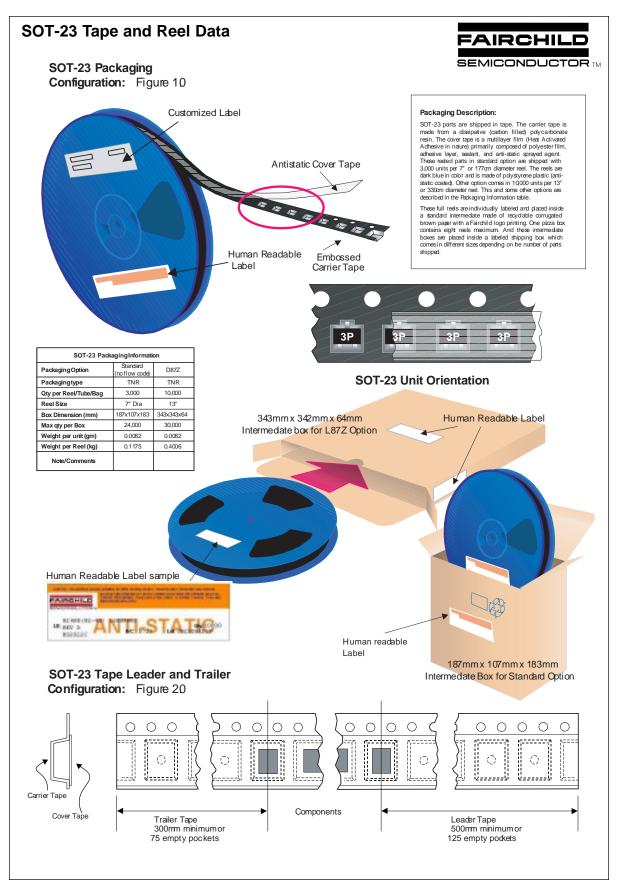


TO-92 Package Dimensions FAIRCHILD SEMICONDUCTOR TM TO-92 (FS PKG Code 92, 94, 96) Scale 1:1 on letter size paper Dimensions shown below are in: inches [millimeters] Part Weight per unit (gram): 0.1977 0.185 4.70 0.170 4.32 TO-92 (92,94,96) 94 96 B F В В В D D 2 В S С G Ε Ø0.060 [Ø1.52] G В S С G 0.010 [0.254] DEEP 5.0°TYP.

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0.095 0.084 2.13

January 2000, Rev. B

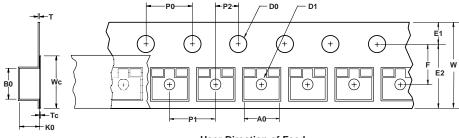


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SOT-23 Tape and Reel Data, continued

SOT-23 Embossed Carrier Tape

Configuration: Figure 3.0



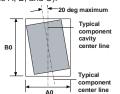
User Direction of Feed	

	Dimensions are in millimeter													
Pkg type	Α0	В0	w	D0	D1	E1	E2	F	P1	P0	K0	Т	Wc	Тс
SOT-23 (8mm)	3.15 +/-0.10	2.77 +/-0.10	8.0 +/-0.3	1.55 +/-0.05	1.125 +/-0.125	1.75 +/-0.10	6.25 min	3.50 +/-0.05	4.0 +/-0.1	4.0 +/-0.1	1.30 +/-0.10	0.228 +/-0.013	5.2 +/-0.3	0.06 +/-0.02

Notes: A0, B0, and K0 dimensions are determined with respect to the EIA/Jedec RS-481 rotational and lateral movement requirements (see sketches A, B, and C).



Sketch A (Side or Front Sectional View)
Component Rotation



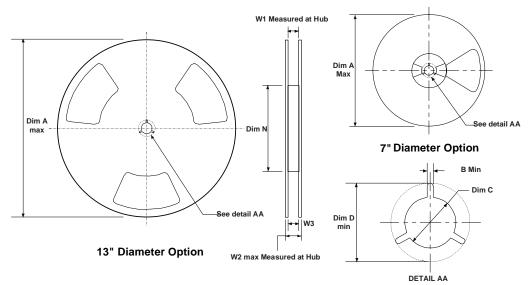
Sketch B (Top View)
Component Rotation



Sketch C (Top View)

Component lateral movement

SOT-23 Reel Configuration: Figure 4.0

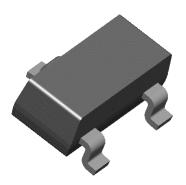


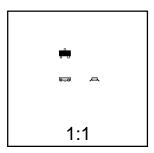
	Dimensions are in inches and millimeters								
Tape Size	Reel Option	Dim A	Dim B	Dim C	Dim D	Dim N	Dim W1	Dim W2	Dim W3 (LSL-USL)
8mm	7" Dia	7.00 177.8	0.059 1.5	512 +0.020/-0.008 13 +0.5/-0.2	0.795 20.2	2.165 55	0.331 +0.059/-0.000 8.4 +1.5/0	0.567 14.4	0.311 - 0.429 7.9 - 10.9
8mm	13" Dia	13.00 330	0.059 1.5	512 +0.020/-0.008 13 +0.5/-0.2	0.795 20.2	4.00 100	0.331 +0.059/-0.000 8.4 +1.5/0	0.567 14.4	0.311 - 0.429 7.9 - 10.9

SOT-23 Package Dimensions



SOT-23 (FS PKG Code 49)

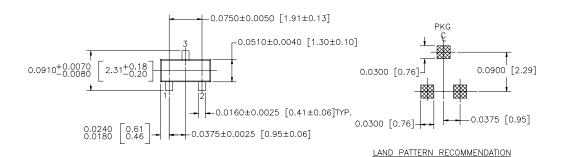


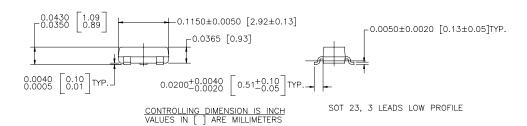


Scale 1:1 on letter size paper

Dimensions shown below are in: inches [millimeters]

Part Weight per unit (gram): 0.0082





NOTE: UNLESS OTHERWISE SPECIFIED

- 1. STANDARD LEAD FINISH 150 MICROINCHES / 3.81 MICROMETERS MINIMUM TIN / LEAD (SOLDER) ON ALLOY 42
- 2. REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE G, DATED JUL 1993

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